



Cite this: *J. Mater. Chem. C*, 2025,
13, 16302

DOI: 10.1039/d5tc90119g

rsc.li/materials-c

Correction: Heterogeneous integration of 8-inch LiNbO₃ films for second harmonic generation

Yong Wang,^a Zi Wang,^b Yang Liu,^a Lina Yang,^a Kaixuan He,^{*a} Lifan Zhang,^a Guodong Wang^{*b} and Lei Zhang^b

Correction for 'Heterogeneous integration of 8-inch LiNbO₃ films for second harmonic generation' by Yong Wang *et al.*, *J. Mater. Chem. C*, 2025, <https://doi.org/10.1039/d5tc01952d>.

The authors regret that Fig. 4 was inadvertently replaced with a copy of Fig. 5. The correct version of Fig. 4 is shown in this notice.

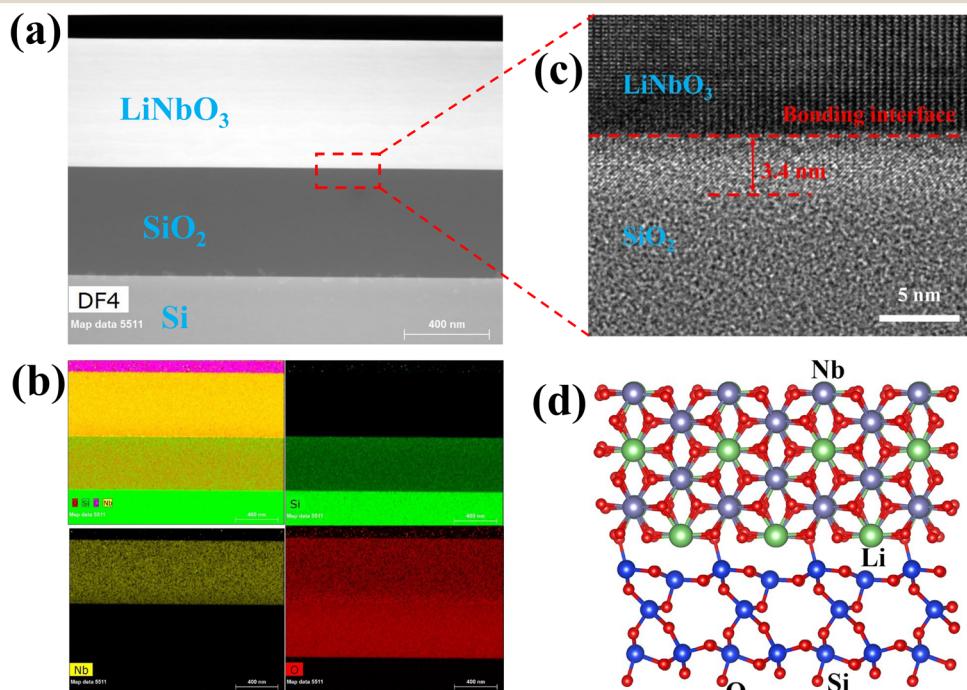


Fig. 4 Cross-section of 8-inch heterogeneous integrated LN wafers: (a) TEM result; (b) EDS mapping results; (c) HRTEM result; (d) atomic structure diagram.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

^a East China Institute of Photo-Electron IC, Bengbu 233000, China. E-mail: hekxsr@163.com

^b State Key Laboratory of Crystal Material and Institute of Novel Semiconductors, Shandong University, Jinan, 250100, P. R. China. E-mail: guodong9631@sdu.edu.cn

